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Correction: High-performance one-dimensional halide perovskite crossbar memristors and synapses for neuromorphic computing

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The authors regret an error in the Acknowledgements section of the published article, in which an incorrect project code number was reported for the Competitive Research Programme (CRP): “NRF-CRP14-2014-03” should be replaced with “NRF-CRP25-2020-0002”.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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